OCTAL BUS SCHMITT-TRIGGER TRANSCEIVER; 3-STATE

FEATURES

- **Octal bidirectional bus interface**
- **Non-inverting 3-state outputs**
- **Output capability: bus driver**
- **I_{CC} category: MSI**
- **Schmitt-trigger action on all data inputs**

GENERAL DESCRIPTION

The 74HC/HCT7245 are high-speed Si-gate CMOS devices and are pin compatible with low power Schottky TTL (LSTTL). They are specified in compliance with JEDEC standard no. 7A.

The 74HC/HCT7245 are octal transceivers featuring non-inverting 3-state bus compatible outputs in both send and receive directions. The "7245" features and output enable ($\overline{OE}$) input for easy cascading and a send/receive input (DIR) for direction control. $\overline{OE}$ controls the outputs so that the buses are effectively isolated. The 74HC/HCT7245 have Schmitt-trigger inputs. These inputs are capable of transforming slowly changing input signals into sharply defined jitter-free output signals.

The "7245" is identical to the "245" but has hysteresis on the data inputs.

FUNCTION TABLE

INPUTS		INPUTS/OUTPUTS	
$\overline{OE}$	DIR	A_n	B_n
L	L	A = B	inputs
L	H	inputs	B = A
H	X	Z	Z

H = HIGH voltage level
L = LOW voltage level
X = don't care
Z = high impedance OFF-state

SYMBOL	PARAMETER	CONDITIONS	TYPICAL		UNIT
			HC	HCT	
t_{PHL}/t_{PLH}	propagation delay A_n to B_n	C_L = 15 pF V_{CC} = 5 V	8	12	ns
C_I	input capacitance		3.5	3.5	pF
$C_{I/O}$	input/output capacitance		10	10	pF
C_{PD}	power dissipation capacitance per transceiver	notes 1 and 2	40	40	pF

GND = 0 V; T_{amb} = 25 °C; $t_r = t_f$ = 6 ns

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in µW):
   $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:
   f_i = input frequency in MHz
   f_o = output frequency in MHz
   $\Sigma (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs
   C_L = output load capacitance in pF
   V_{CC} = supply voltage in V
2. For HC the condition is V_I = GND to V_{CC}
   For HCT the condition is V_I = GND to V_{CC} − 1.5 V

PACKAGE OUTLINES

SEE PACKAGE INFORMATION SECTION

PIN DESCRIPTION

PIN NO.	SYMBOL	NAME AND FUNCTION
1	DIR	direction control
2, 3, 4, 5, 6, 7, 8, 9	A_0 to A_7	data inputs/outputs
10	GND	ground (0 V)
18, 17, 16, 15, 14, 13, 12, 11	B_0 to B_7	data inputs/outputs
19	$\overline{OE}$	output enable input (active LOW)
20	V_{CC}	positive supply voltage

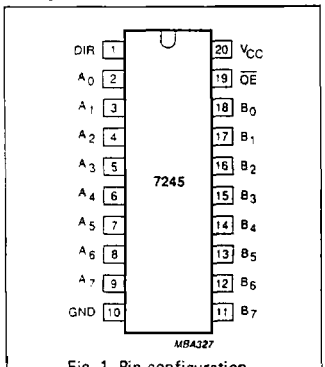

Fig. 1 Pin configuration.

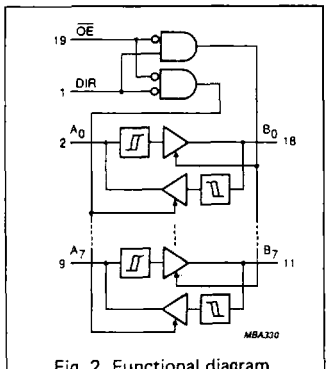

Fig. 2 Functional diagram.

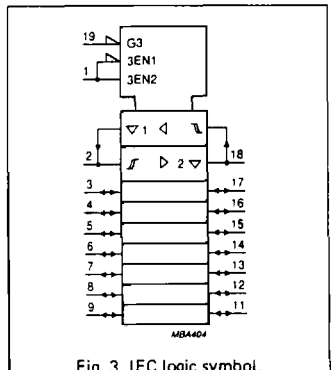

Fig. 3 IEC logic symbol.

DC CHARACTERISTICS FOR 74HC

For the DC characteristics see chapter "HCMOS family characteristics", section "Family specifications".

Output capability: bus driver
I_{CC} category: MSI

TRANSFER CHARACTERISTICS FOR 74HC

Voltages are refered to GND (ground = 0 V)

SYMBOL	PARAMETER	T_{amb} (°C)							UNIT	TEST CONDITIONS	
		74HC								V_{CC} V	WAVEFORMS
		+25			−40 to +85		−40 to +125				
		min.	typ.	max.	min.	max.	min.	max.			
V_{T+}	positive-going threshold			1.50 3.15 4.20		1.50 3.15 4.20		1.50 3.15 4.20	V	2.0 4.5 6.0	Figs. 4 and 5
V_{T-}	negative-going threshold	0.30 1.35 1.80			0.30 1.35 1.80		0.30 1.35 1.80		V	2.0 4.5 6.0	Figs. 4 and 5
V_H	hysteresis ($V_{T+} - V_{T-}$)	0.1 0.25 0.3	0.2 0.4 0.5		0.1 0.25 0.3		0.1 0.25 0.3		V	2.0 4.5 6.0	Figs. 4 and 5

AC CHARACTERISTICS FOR 74HC

GND = 0 V; $t_r = t_f$ = 6 ns; C_L = 50 pF

SYMBOL	PARAMETER	T_{amb} (°C)							UNIT	TEST CONDITIONS	
		74HC								V_{CC} V	WAVEFORMS
		+25			−40 to +85		−40 to +125				
		min.	typ.	max.	min.	max.	min.	max.			
t_{PHL}/ t_{PLH}	propagation delay A_n to B_n; B_n to A_n		33 12 10	100 20 17		125 25 21		150 30 26	ns	2.0 4.5 6.0	Fig. 6
t_{PZH}/ t_{PZL}	3-state output enable time $\overline{OE}$ to A_n; $\overline{OE}$ to B_n		47 17 14	160 32 27		200 40 34		240 48 41	ns	2.0 4.5 6.0	Fig. 7
t_{PHZ}/ t_{PLZ}	3-state output disable time $\overline{OE}$ to A_n; $\overline{OE}$ to B_n		52 19 16	160 32 27		200 40 34		240 48 41	ns	2.0 4.5 6.0	Fig. 7
t_{THL}/ t_{TLH}	output transition time		14 5 4	60 12 10		75 15 13		90 18 15	ns	2.0 4.5 6.0	Fig. 6

DC CHARACTERISTICS FOR 74HCT

For the DC characteristics see chapter "HCMOS family characteristics", section "Family specifications".

Output capability: bus driver
I_{CC} category: MSI

Note to HCT types

The value of additional quiescent supply current (ΔI_{CC}) for a unit load of 1 is given in the family specifications. To determine ΔI_{CC} per input, multiply this value by the unit load coefficient shown in the table below.

INPUT	UNIT LOAD COEFFICIENT
A_n	0.33
B_n	0.33
$\overline{OE}$	1.50
DIR	1.00

TRANSFER CHARACTERISTICS FOR 74HCT

Voltages are refered to GND (ground = 0 V)

SYMBOL	PARAMETER	T_{amb} (°C)							UNIT	TEST CONDITIONS	
		74HCT								V_{CC} V	WAVEFORMS
		+25			−40 to +85		−40 to +125				
		min.	typ.	max.	min.	max.	min.	max.			
V_{T+}	positive-going threshold			2.0 2.1		2.0 2.1		2.0 2.1	V	4.5 5.5	Figs. 4 and 5
V_{T-}	negative-going threshold	0.7 0.8			0.64 0.74		0.6 0.7		V	4.5 5.5	Figs. 4 and 5
V_H	hysteresis ($V_{T+} - V_{T-}$)	0.17 0.17	0.23 0.23						V	4.5 5.5	Figs. 4 and 5

AC CHARACTERISTICS FOR 74HCT

GND = 0 V; $t_r = t_f$ = 6 ns; C_L = 50 pF

SYMBOL	PARAMETER	T_{amb} (°C)							UNIT	TEST CONDITIONS	
		74HCT								V_{CC} V	WAVEFORMS
		+25			−40 to +85		−40 to +125				
		min.	typ.	max.	min.	max.	min.	max.			
t_{PHL}/ t_{PLH}	propagation delay A_n to B_n; B_n to A_n		17	30		37		45	ns	4.5	Fig. 6
t_{PZH}/ t_{PZL}	3-state output enable time $\overline{OE}$ to A_n; $\overline{OE}$ to B_n		19	32		40		48	ns	4.5	Fig. 7
t_{PHZ}/ t_{PLZ}	3-state output disable time $\overline{OE}$ to A_n; $\overline{OE}$ to B_n		19	32		40		48	ns	4.5	Fig. 7
t_{THL}/ t_{TLH}	output transition time		5	12		15		18	ns	4.5	Fig. 6

TRANSFER CHARACTERISTIC WAVEFORMS

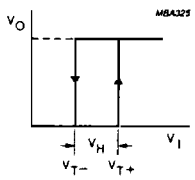

Fig. 4 Transfer characteristic.

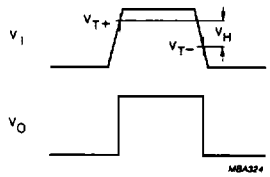

Fig. 5 Waveforms showing the definition of V_{T+}, V_{T-} and V_H.

AC WAVEFORMS

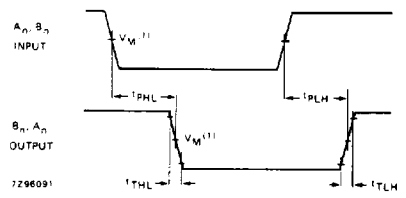

Fig. 6 Waveforms showing the input (A_n, B_n) to output (B_n, A_n) propagation delays and the output transition times.

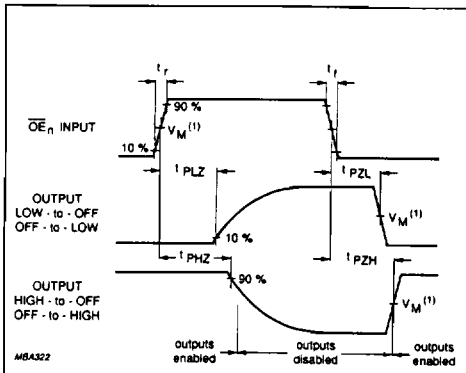

Fig. 7 Waveforms showing the 3-state enable and disable times.

Note to AC waveforms

(1) HC : V_M = 50%; V_I = GND to V_{CC}.
HCT: V_M = 1.3 V; V_I = GND to 3 V.